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Study of Cr₅Si₃ Electrodes on Langasite Surface Acoustic Wave **Resonators for High Temperature Sensing**

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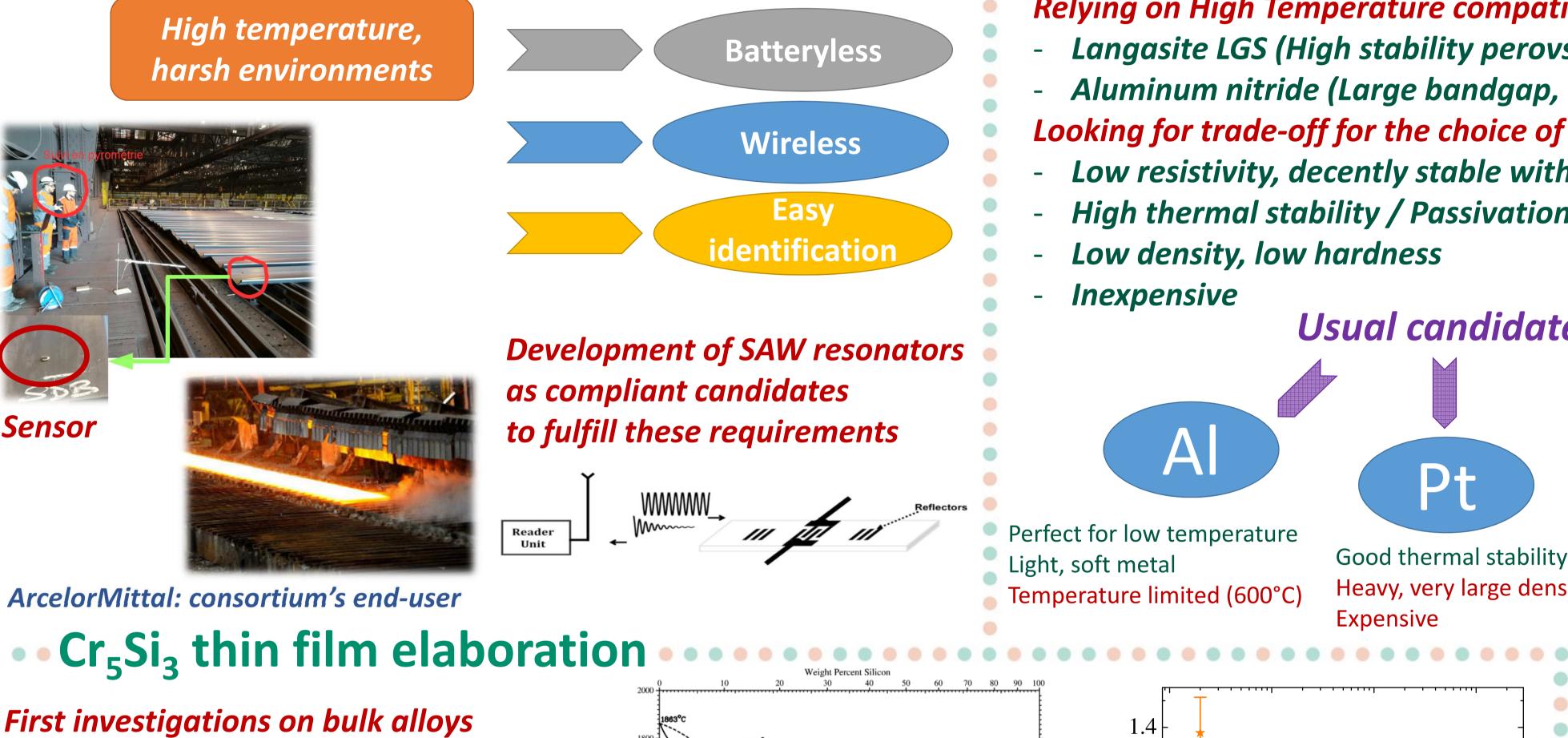
Abstract

Sensor

Many piezoelectric materials are viewed as potential candidates for high temperature SAW applications, including langasite (LGS) and AIN. Only a few metals or alloys can withstand such temperatures, among them platinum and iridium based alloys or nanocomposites. These materials cannot be considered when high quality factors are required, due to their higher resistivity and density. The (Cr, V)-Si system was previously studied, but has never been proposed as a solution for SAW electrodes, in spite of its high thermal stability, lower density (about 6 g/cm³) and decent resistivity. This study focuses on the development of Cr₅Si₃ alloy deposition for its use in LGSbased resonators, aiming at wireless applications.



Context for High Temperature Sensing



Reaching trade-offs for IDT electrodes

- Relying on High Temperature compatible piezoelectric substrates
- Langasite LGS (High stability perovskite, parabolic temperature behavior)
- Aluminum nitride (Large bandgap, high resistivity semiconductor, linear TCF) Looking for trade-off for the choice of IDT electrodes
- Low resistivity, decently stable with temperature
- High thermal stability / Passivation

Usual candidates

10

80

DRX results for $Cr_5 Si_3$ on LGS

Temperature (°C)

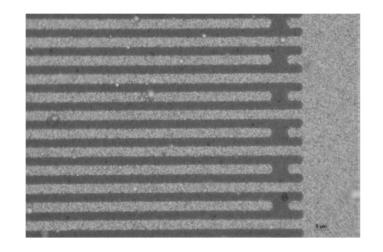
100

100

-LGS

Heavy, very large density

Medium thermal stability Large density



Typical Aluminum IDTs Other candidates to explore: Cr-Si alloys

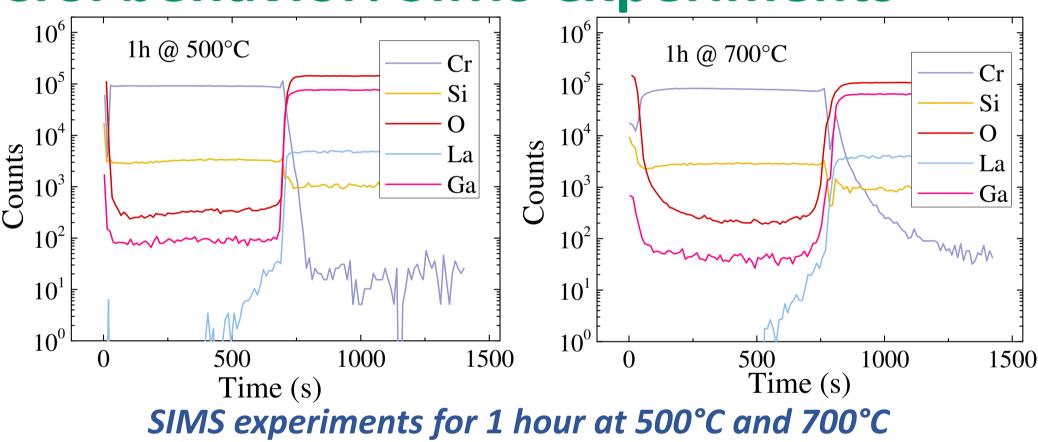
Lower density than most metals / semi-metal alloys More resistive than Pt...

...But more steady with temperature than Al Might be prone to diffusion...

...But expected to have good thermal stability

Trade-off to be investigated

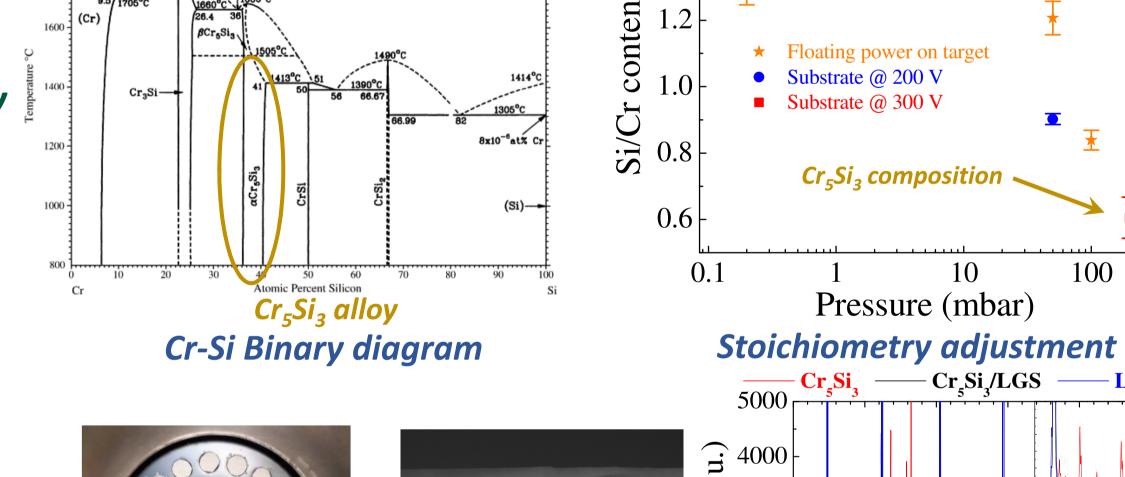




Alloys prepared in electric arc furnace Samples followed by Thermogravimetry

Cr₅Si₃ selected as trade-off between low density and high temperature stability

Investigated system: Cr-Si



Investigation of Cr₅Si₃ for thin films

- Prepared by DC sputtering from Cr-Si target
- **Optimization of parameters:**
 - Power on target
 - Floating / Set potentials on substrate
 - Chamber pressure...

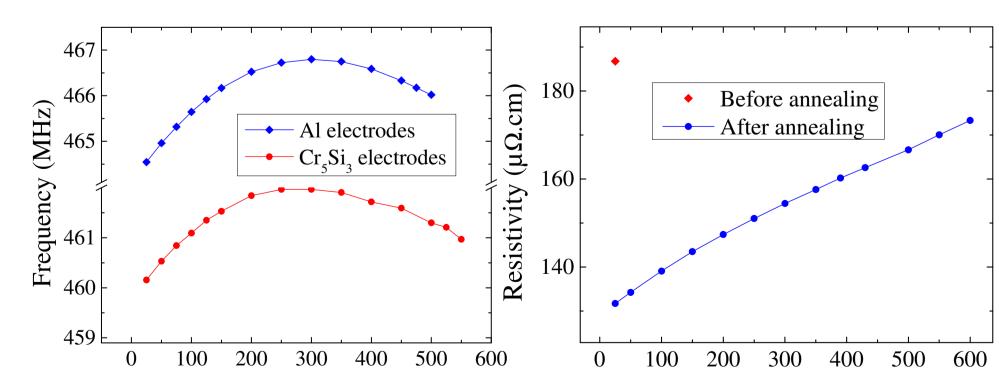




• High Temperature SAW characterizations

Resonator design for first HT experiments

- Synchronous design
- Wavelengths between 5 and 16 µm
- Aperture = $40 \cdot \lambda$, 100 pairs, 2 x 200 reflectors
- Electrodes choice: Cr₅Si₃, 200 nm



3000

Su 2000

1000

SIMS experiments after 1 hour

- Diffusion into LGS is very limited, up to 600°C
- Slight surface oxidation

SIMS experiments after 6 hours

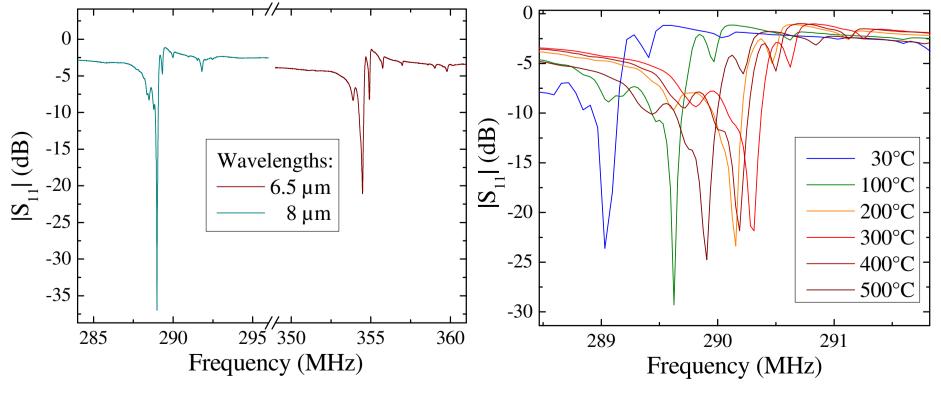
- No further diffusion into LGS
- Oxidation layer is strongly slowed down
- Good potential for light, stable electrodes up to 600°C

Conclusion and perspectives

Exploration of Cr₅Si₃ for SAW resonator electrodes

- Approach: reaching a good trade-off between temperature range, low resistivity, low density, thermal stability...
- Cr₅Si₃ shows good thermal stability up to 600°C
- Resistivity remains high, but rather steady with temperature

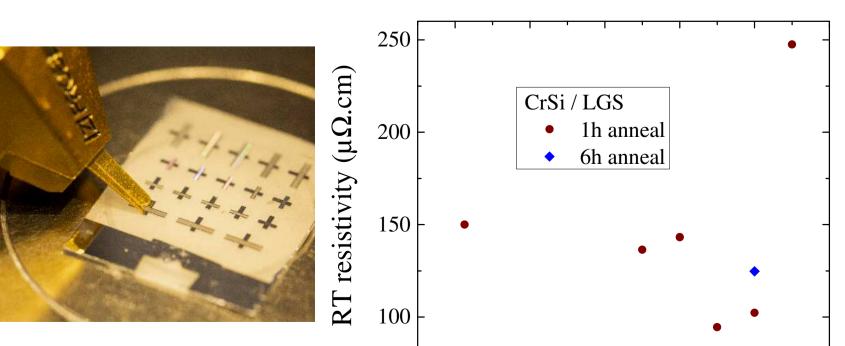
Future strategies for the improvement of Cr₅Si₃ *electrodes* Initial anneal of electrodes, for better thermal stability



Room Temperature and High Temperature behaviors of LGS resonators with Cr₅Si₃ electrodes

- *Measurements up to 550°C achieved with Cr₅Si₃ electrodes*
- Higher resistivity than Pt, but reasonable steadyness with temperature
- 1-hour and 6-hour long anneals at 600°C exhibit comparatively lower resistivities: *importance of initial anneal of electrodes*

Temperature (°C) Frequency behavior of LGS-based Resistivity monitoring resonators: Cr₅Si₃ vs Al electrodes of Cr₅Si₃ IDT electrodes



RF characterizations

600 800 Anneal temperature (°C) Van der Pauw Resistivity on thin films of Cr₅Si₃

- Integration of a passivation layer
- Study of Cr₅Si₃ with substrates less prone to interdiffusion (AIN / Sapphire...)
- **Extension to Cr-V-Si ternary alloys**

Future work on integration of Cr₅Si₃ electrodes

- **Optimization of LGS-based and AIN-based resonators** equipped with Cr₅Si₃ electrodes
- *Further work on* Cr₅Si₃ aging behavior

Other study on AIN / Sapphire optimization for wireless HT SAW sensors (IUS 2018 Poster)

Optimization of Al/AlN/Sapphire Acoustic Wave Sensors for High Temperature Wireless Applications

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